

Fig. S1 UV-vis absorption spectra of TiO<sub>2</sub> via different concentration of MCA modification.

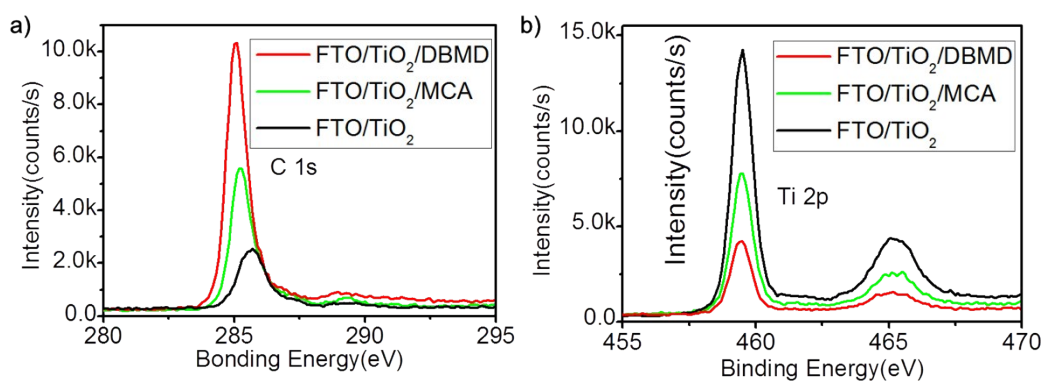


Fig. S2 Surface XPS analyses of a) carbon (285.0 eV (C1s)) and b) titanium (464.5 eV, 2p<sub>1/2</sub>, 458.8 eV, 2p<sub>3/2</sub>) from FTO/TiO<sub>2</sub> and FTO/TiO<sub>2</sub>/MCA substrates.

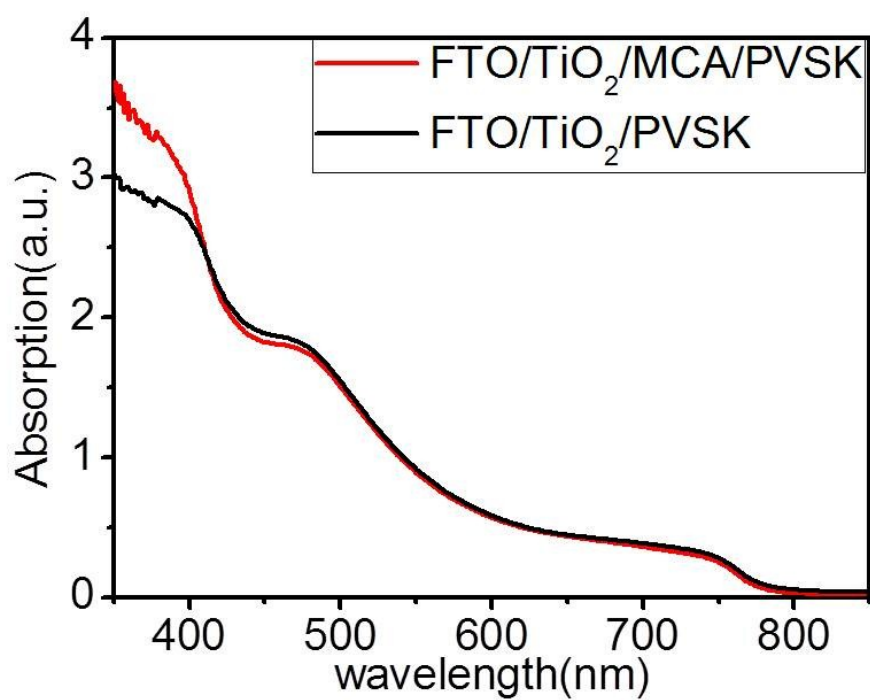


Fig. S3 Absorption spectra of perovskite film grown on  $\text{TiO}_2$  and  $\text{TiO}_2/\text{MCA}$ .

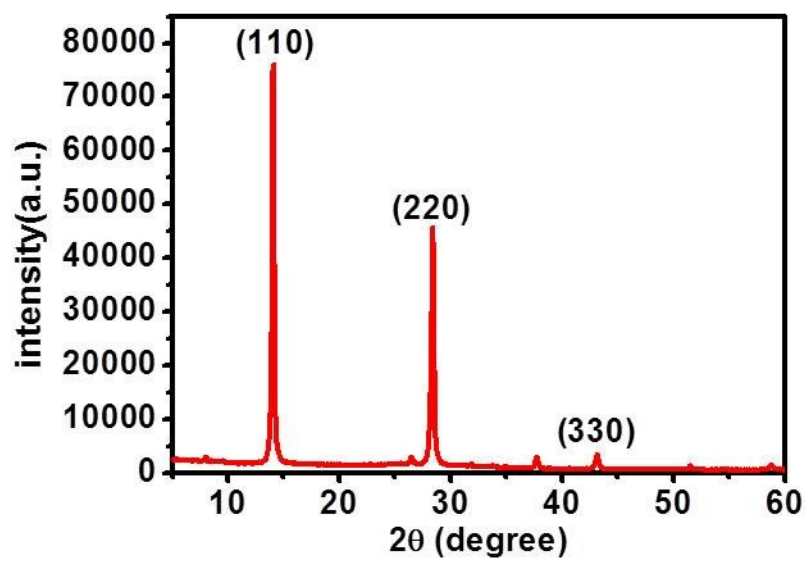


Fig. S4 XRD-pattern of the perovskite films grown on  $\text{TiO}_2$  with MCA modification.

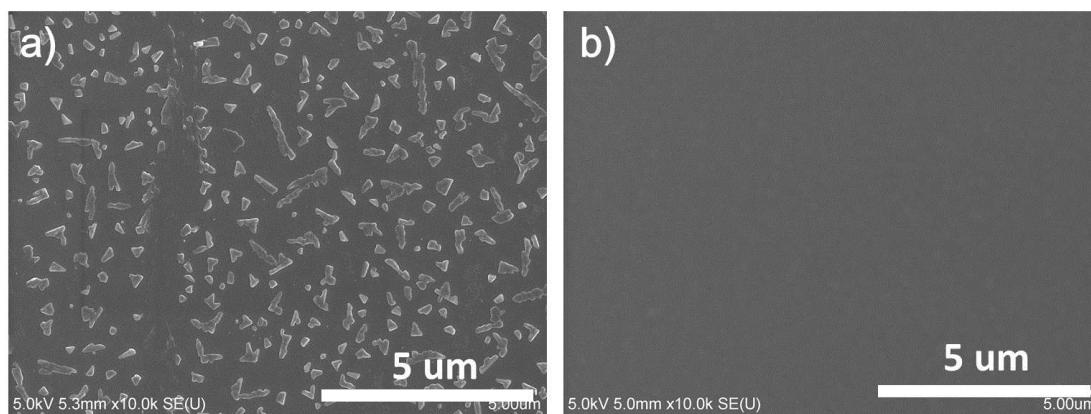


Fig. S5 SEM images of different substrate at the same scale a) FTO/ TiO<sub>2</sub>, b) FTO/ TiO<sub>2</sub>/MCA.

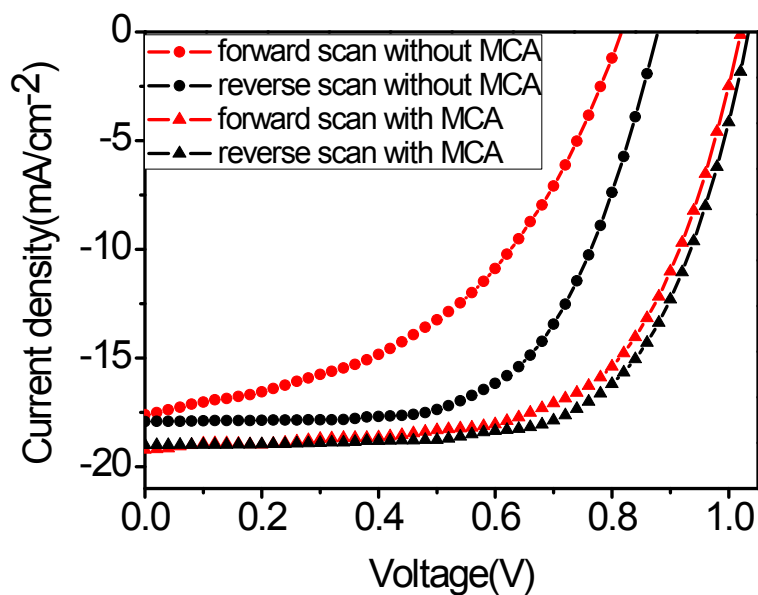


Fig. S6  $J$ - $V$  curves of larger active area cell from forward and reverse scan with and without MCA modification, with a delay time of 20 ms and a voltage step of 0.02 V s<sup>-1</sup>.

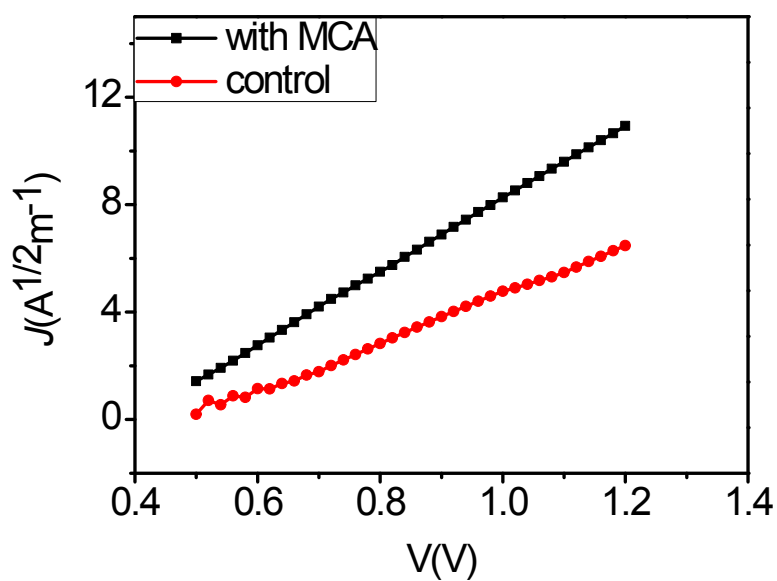


Fig. S7  $J$ - $V$  characteristics under dark for electron-only devices based on with and without MCA with the structure of FTO/ TiO<sub>2</sub>/PVSK/PCBM/Ag.

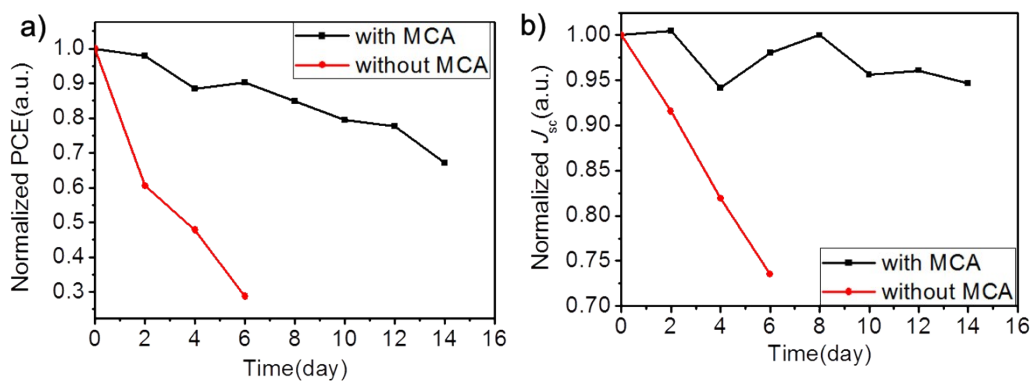


Fig. S8 Long-term stability tests of devices modified with MCA using forward scan mode.

**Different concentrations of DBMB**

Device	Voc(V)	Jsc(mA/cm <sup>2</sup> )	FF	PCE(%) Average
Control	0.987	12.5	26.59	3.29
	1.18	11.8	47.13	5.54
3mg/ml	0.988	19.3	43.81	8.35
	1.05	19.6	56.4	11.58
6mg/ml	1.09	19.7	64.60	13.85
	1.09	19.9	65.12	14.07
9mg/ml	1.16	18.3	66.66	14.14
	1.15	19.2	65.11	14.37
12mg/ml	1.07	18.9	59.78	12.16
	1.08	18.9	62.32	12.75

Table 1. Effect of MCA concentration on the performance of CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub> solar cells

Device	Voc(V)	Jsc(mA/cm <sup>2</sup> )	FF	PCE(%) Best
c-TiO <sub>2</sub> (FS)	0.81 ± 0.01(0.82)	16.58 ± 1.03(17.61)	49.21 ± 2.43(46.78)	6.62 ± 0.11(6.73)
c-TiO <sub>2</sub> (RS)	0.83 ± 0.05(0.80)	18.06 ± 0.22(17.84)	55.28 ± 7.66(62.94)	8.30 ± 1.56(9.86)
c-TiO <sub>2</sub> /MCA(FS)	1.02 ± 0.03(1.05)	19.20 ± 0.25(19.45)	63.20 ± 2.03(61.17)	12.39 ± 0.1(12.49)
c-TiO <sub>2</sub> /MCA(RS)	1.03 ± 0.04(1.07)	18.96 ± 0.45(19.41)	66.15 ± 1.19(64.96)	12.97 ± 0.47(13.44)

Table 2. The performance of the devices with larger active area.